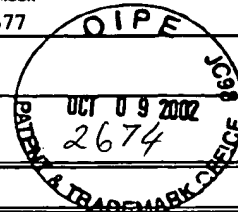


Form PTO 1449  U.S. Department of Commerce Patent and Trademark Office  Information Disclosure Statement by Applicant	ATTY. DOCKET NUMBER NITT.0057	SERIAL NUMBER 10/031,377
	APPLICANT SUZUKI et al.	
	FILING DATE April 12, 2002	GROUP



#### U.S. Patent Documents

Examiner Initial	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBC LASS	FILING DATE
Kmn	5,600,343	2/4/97	Sarrasin	345	75.2	4/27/95

#### Foreign Patent Documents

Examiner Initial	DOCUMENT NUMBER	FILING DATE	COUNTRY	CLASS	SUB-CLASS	TRANSLATION	
						YES	NO
Kmn	2-184890	1/12/89	Japan				X
Kmn	8-305317	4/28/95	Japan				X
Kmn	62-8340	7/4/85	Japan				X
Kmn	EP 0 597 772 A1	11/9/93	EPO				X
Kmn	2 698 201	11/13/92	France				X
Kmn	2000-206925	1/13/99	Japan				X

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#### Other Documents (Including Author, Title, Date Pertinent Pages, Etc.)

International Search Report from Japanese Patent Office dated November 27, 2000		OCT 15 2002
Technology Center 2000		
EXAMINER Kevin M. Nguyen	DATE CONSIDERED 3/10/2006	
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FILING DATE		GROUP		
Concurrently Herewith		2674		

U.S. Patent Documents

Examiner Initial	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBC LASS	FILING DATE

Foreign Patent Documents

Examiner Initial		DOCUMENT NUMBER	FILING DATE	COUNTRY	CLAS S	SUB- CLASS	TRANSLATION	
							YES	NO

Other Documents (Including Author, Title, Date Pertinent Pages, Etc.)

Kmn	Kuniyoshi Yokoo, Hiroshi Tanaka, Shinji Sato, Junichi Murota, and Shoichi Ono, "Emission Characteristics of Metal-Oxide-Semiconductor Electron tunneling Cathode", J. Vac. Sci. Technol. B 11(2), Mar/Apr 1993, pp. 429-432
Kmn	Nobuyasu Negishi, Takashi Chuman, Shingo Iwasaki, Takamasa Yoshikawa, Hiroshi Ito and Kiyohide Ogasawara, "High Efficiency Electron-Emission in Pt/SiO <sub>2</sub> /Si/Al Structure", Jpn. J. Appl. Phys. Vol 36 (1997), 15 July 1997, pp. 939-941
Kmn	Nobuyoshi Koshida, Tsuyoshi Ozaki, Xia Sheng, and Hideki Koyama, "Cold Electron Emission from Electroluminescent Porous Silicon Diodes", Jpn. J. Appl. Phys. Vol 34 (1995), 1 June 1995, pp. 705-707.
EXAMINER	DATE CONSIDERED
Kevin M. Nguyen	3/10/2006

EXAMINER: Initial if citation is considered, whether or not citation is in conformance with MPEP 609; draw a line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant

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